



#### 100V N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	Max R <sub>DS(on)</sub>	Max I <sub>D</sub> T <sub>A</sub> = 25°C (Note 5)	
100V	250mΩ @ V <sub>GS</sub> = 10V	1.9A	
	300mΩ @ V <sub>GS</sub> = 6V	1.68A	

### **Description and Applications**

This MOSFET features a unique structure, combining the benefits of low on-resistance and fast switching, making it ideal for high-efficiency, power management applications.

- DC DC Converters
- Power Management Functions
- Disconnect Switches
- Motor Control

### **Features and Benefits**

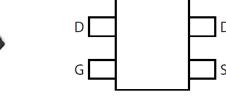
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

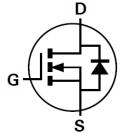
#### **Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208(2)
- Weight: 0.015 grams (Approximate)









Top View

Pinout Top-view

Device symbol

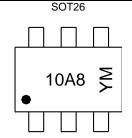
# **Ordering Information** (Note 4)

Part Number	Reel Size (inch)	Tape Width (mm)	Quantity Per Reel
ZXMN10A08E6TA	7	8	3000
ZXMN10A08E6TC	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

#### **Marking Information**



10A8 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Year	201	5	2016	2017	2018	2019	2020	202	1 20	22 2	2023	2024	2025
Code	С		D	Е	F	G	Н			J	K	L	М
Month	ı	Jar	n Fel	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	)	1	2	3	4	5	6	7	8	9	0	N	D



#### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

	Characteristic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	100	V
Gate-Source Voltage			V <sub>GS</sub>	±20	V
Continuous Drain Current		Note 5)		1.9	
	1/ 101/	T <sub>A</sub> =+70°C (Note 5)	I <sub>D</sub>	1.5	٨
	$V_{GS} = 10V$	(Note 4)		1.5	Α
		(Note 7)		3.5	
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	8.6	А
Continuous Source Current (Body Diode) (Note 5)			I <sub>S</sub>	2.5	Α
Pulsed Source Current (Body Diode) (Note 6)			I <sub>SM</sub>	8.6	А

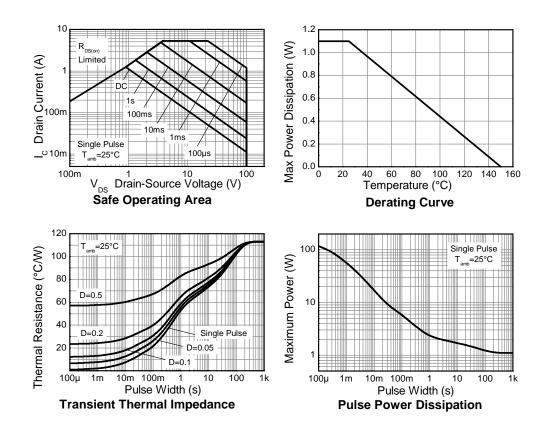
### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
	(Note 4)		1.1		
Power Dissipation	(Note 5)	(Note 5) P <sub>D</sub>		W	
	(Note 7)		6.3		
The arms of Decistance . It was time to Americant	(Note 4)	1	114	°C/W	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	73.5		
Thermal Resistance, Junction to Leads	$R_{ heta JL}$	19.7	°C/W		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

Notes:

- 4. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- 5. For a device surface mounted on FR4 PCB measured at t ≤ 5 sec.
- 6. Repetitive rating 25mm x 25mm FR4 PCB, D = 0.02, pulse width 300µs pulse width limited by maximum junction temperature.
- 7. Thermal resistance from junction to solder-point (at the end of the drain lead).

#### **Thermal Characteristics**





# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

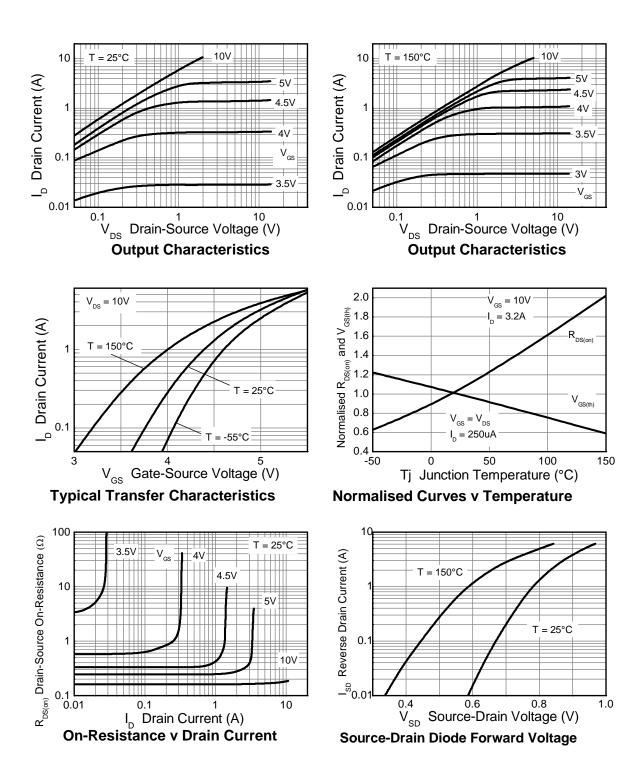
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	$I_D = 250 \mu A, V_{GS} = 0 V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	0.5	μА	$V_{DS} = 100V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(th)</sub>	2.0		4.0	V	$I_D = 250 \mu A, V_{DS} = V_{GS}$	
Static Drain-Source On-Resistance (Note 8)	P-a (a)			0.25	Ω	$V_{GS} = 10V, I_D = 3.2A$	
Static Drain-Source On-Nesistance (Note 6)	R <sub>DS (ON)</sub>			0.30	32	$V_{GS} = 6V, I_D = 2.6A$	
Forward Transconductance (Notes 8 & 10)	<b>g</b> fs		5.0	_	S	$V_{DS} = 15V, I_D = 3.2A$	
Diode Forward Voltage (Note 8)	$V_{SD}$		0.87	0.95	V	$I_S = 3.2A, V_{GS} = 0V$	
Reverse Recovery Time (Note 10)	t <sub>rr</sub>		27	_	ns	1 1 2 4 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
Reverse Recovery Charge (Note 10)	Q <sub>rr</sub>	_	32	_	nC	I <sub>S</sub> = 1.2A, di/dt = 100A/μs	
DYNAMIC CHARACTERISTICS (Note 10)				•		•	
Input Capacitance	Ciss		405	_	pF	., 50,4,14, 0)4	
Output Capacitance	Coss		28.2	_	pF	$V_{DS} = 50V, V_{GS} = 0V$ -f = 1MHz	
Reverse Transfer Capacitance	Crss		14.2	_	pF	1 = 11/1112	
Gate Charge (Note 9)	Qg		4.2	_	nC	$V_{GS} = 5V, V_{DS} = 50V$ $I_D = 1.2A$	
Total Gate Charge (Note 9)	Qg	_	7.7	_	nC	10/1/	
Gate-Source Charge (Note 9)	$Q_{gs}$	_	1.8	_	nC	$V_{GS} = 10V, V_{DS} = 50V$	
Gate-Drain Charge (Note 9)	$Q_{gd}$	_	2.1	_	nC	$I_D = 1.2A$	
Turn-On Delay Time (Note 9)	t <sub>d(on)</sub>	_	3.4	_	ns		
Turn-On Rise Time (Note 9)	t <sub>r</sub>		2.2	_	ns	$V_{DD} = 30V, V_{GS} = 10V$	
Turn-Off Delay Time (Note 9)	t <sub>d(off)</sub>	_	8	_	ns	$I_D = 1.2A, R_G \cong 6.0\Omega$	
Turn-Off Fall Time (Note 9)	t <sub>f</sub>		3.2	_	ns	7	

Notes:

<sup>8.</sup> Measured under pulsed conditions. Width ≤300µs. Duty cycle ≤2%.
9. Switching characteristics are independent of operating junction temperature.
10. For design aid only, not subject to production testing.

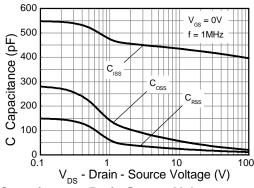


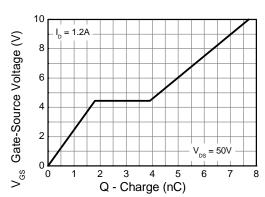
# **Typical Characteristics**





# Typical Characteristics (continued)

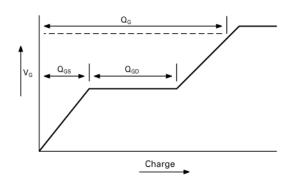




Capacitance v Drain-Source Voltage

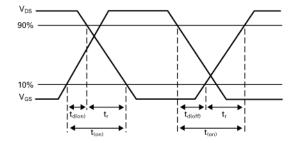
Gate-Source Voltage v Gate Charge

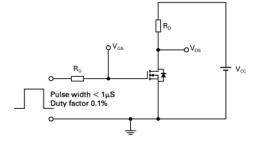
# **Test Circuits**



Current regulator







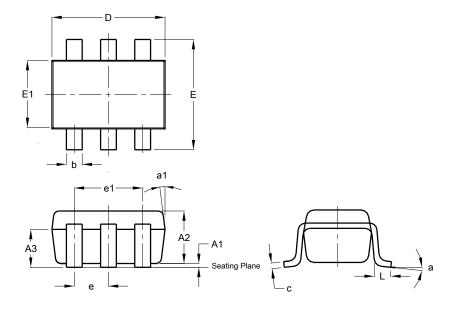
Switching time waveforms

Switching time test circuit



# **Package Outline Dimensions**

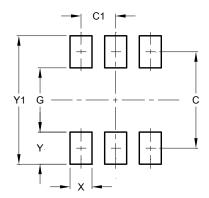
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26						
Dim	Min	Max	Тур				
A1	0.013	0.10	0.05				
A2	1.00	1.30	1.10				
А3	0.70	0.80	0.75				
b	0.35	0.50	0.38				
С	0.10	0.20	0.15				
D	2.90	3.10	3.00				
е	-	-	0.95				
e1	-	-	1.90				
Е	2.70	3.00	2.80				
E1	1.50	1.70	1.60				
L	0.35	0.55	0.40				
а	-	-	8°				
a1	-	-	7°				
All Dimensions in mm							

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Diodes Incorporated: ZXMN10A08E6TA